

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Power Dissipation	P _{PP}	35	W	8/20μs, per Figure 1
Peak Pulse Current	I _{PP}	5	A	8/20μs, per Figure 1
ESD Protection – Contact Discharge	V _{ESD_Contact}	±23	kV	IEC 61000-4-2 Standard
ESD Protection – Air Discharge	V _{ESD_Air}	±25	kV	IEC 61000-4-2 Standard

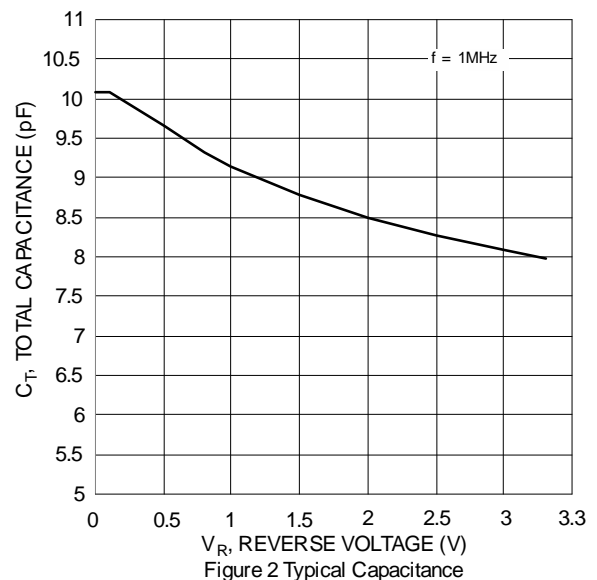
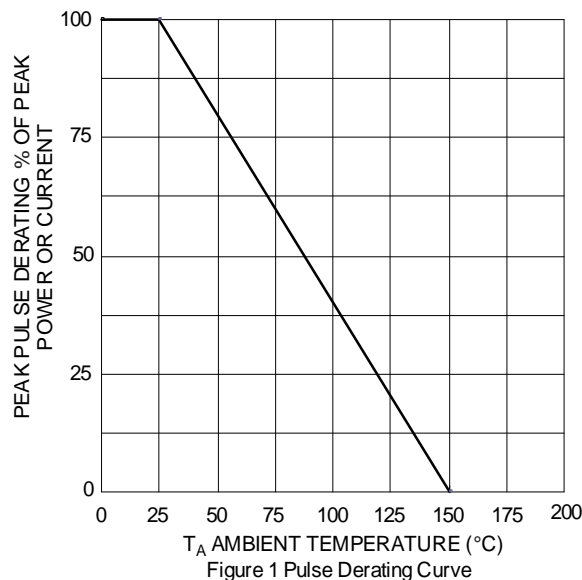
Thermal Characteristics

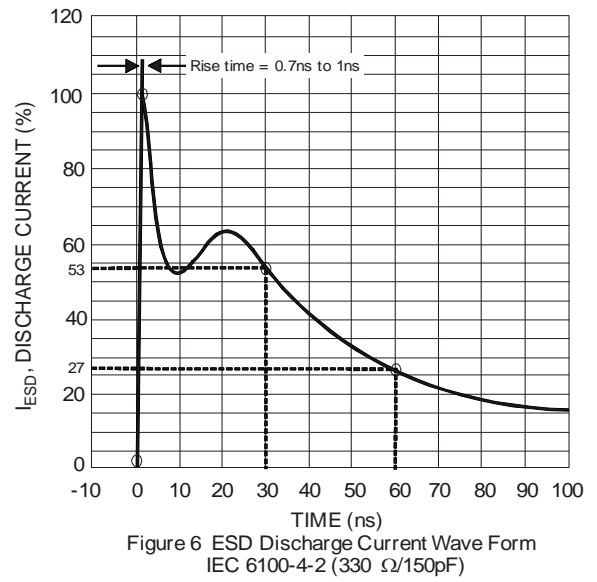
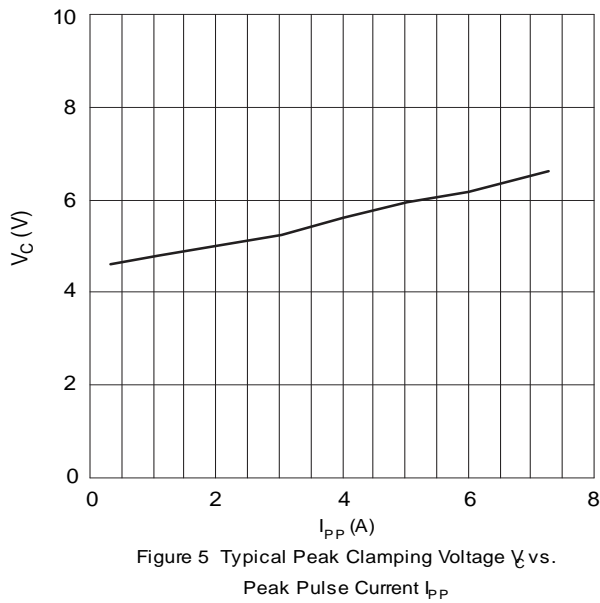
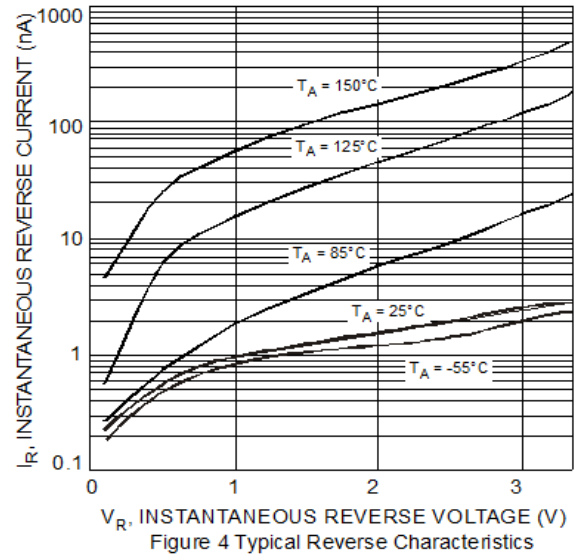
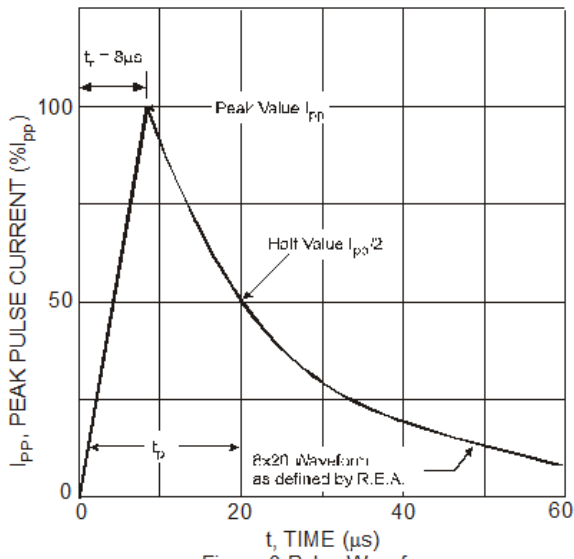
Characteristic	Symbol	Value	Unit
Package Power Dissipation (Note 5)	P _D	250	mW
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	500	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Conditions
Reverse Standoff Voltage	V _{RWM}	—	—	3.3	V	—
Channel Leakage Current (Note 6)	I _{RM}	—	10	200	nA	V _{RWM} = 3.3V
Clamping Voltage, Positive Transients	V _{CL}	—	4.5	5.4	V	I _{PP} = 1A, t _p = 8/20μS
		—	5.8	7.0		I _{PP} = 5A, t _p = 8/20μS
Breakdown Voltage	V _{BR}	3.8	—	6.5	V	I _R = 1mA
Differential Resistance	R _{DIF}	—	0.3	—	Ω	I _R = 1A, t _p = 8/20μS
Channel Input Capacitance	C _{IN}	—	10	13	pF	V _R = 0V, f = 1MHz

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at <http://www.diodes.com>.
 6. Short duration pulse test used to minimize self-heating effect.





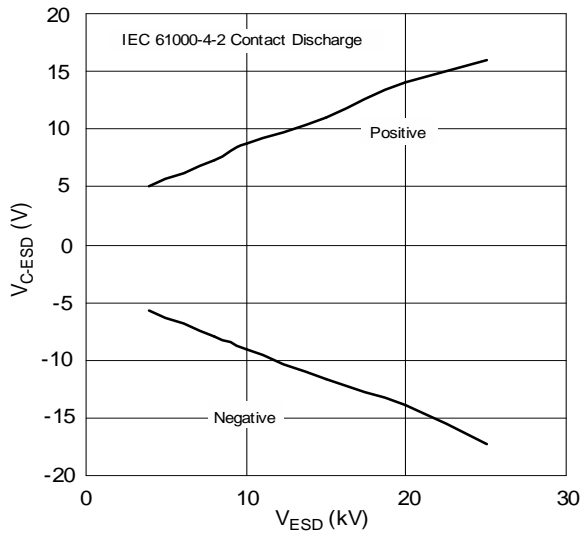


Figure 7 Typical Clamping Voltage vs.
Contact Discharge Voltage

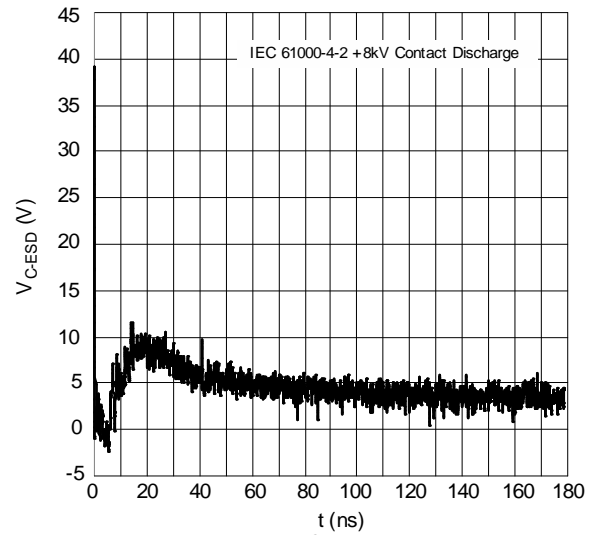


Figure 8 Typical Clamping Performance
@ 8kV Contact Discharge

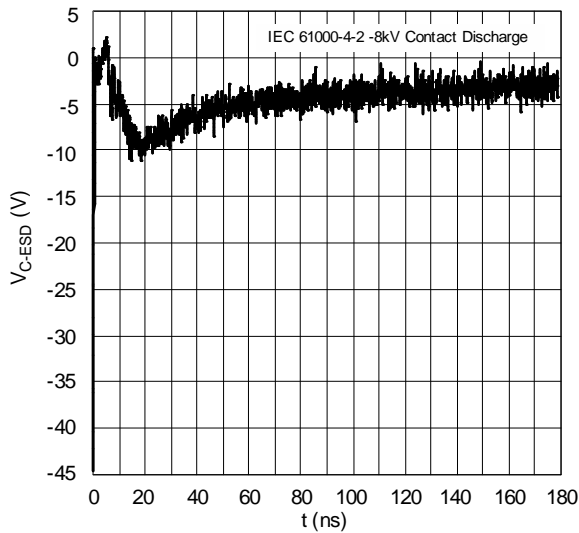
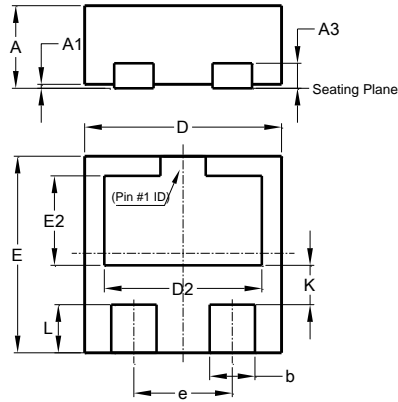


Figure 9 Typical Clamping Performance
@ -8kV Contact Discharge

Package Outline Dimensions

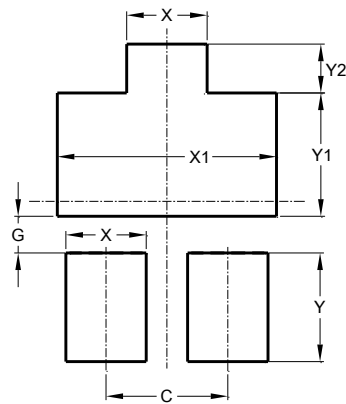
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.



X2-DFN1010-3			
Dim	Min	Max	Typ
A	-	0.40	0.39
A1	0.00	0.05	0.02
A3	-	-	0.13
b	0.18	0.28	0.23
D	0.95	1.05	1.00
D2	0.70	0.90	0.80
E	0.95	1.05	1.00
E2	0.36	0.56	0.46
e	-	-	0.50
K	-	-	0.20
L	0.195	0.295	0.245
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



X2-DFN1010-3	
Dimensions	Value
C	0.500
G	0.150
X	0.330
X1	0.900
Y	0.445
Y1	0.505
Y2	0.200
All Dimensions in mm	

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